

- **Very Low Power Consumption**
– 1 mW Typ at $V_{DD} = 5\text{ V}$
- **Capable of Operation in Astable Mode**
- **CMOS Output Capable of Swinging Rail to Rail**
- **High Output-Current Capability**
– Sink 100 mA Typ
– Source 10 mA Typ
- **Output Fully Compatible With CMOS, TTL, and MOS**
- **Low Supply Current Reduces Spikes During Output Transitions**
- **Single-Supply Operation From 2 V to 15 V**
- **Functionally Interchangeable With the NE555; Has Same Pinout**
- **ESD Protection Exceeds 2000 V Per MIL-STD-883C, Method 3015.2**
- **Available in Q-Temp Automotive High Reliability Automotive Applications Configuration Control/Print Support Qualification to Automotive Standards**

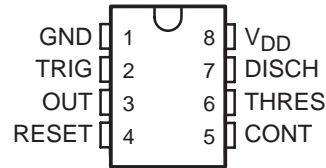
description

The TLC555 is a monolithic timing circuit fabricated using the TI LinCMOS™ process. The timer is fully compatible with CMOS, TTL, and MOS logic and operates at frequencies up to 2 MHz. Because of its high input impedance, this device uses smaller timing capacitors than those used by the NE555. As a result, more accurate time delays and oscillations are possible. Power consumption is low across the full range of power supply voltage.

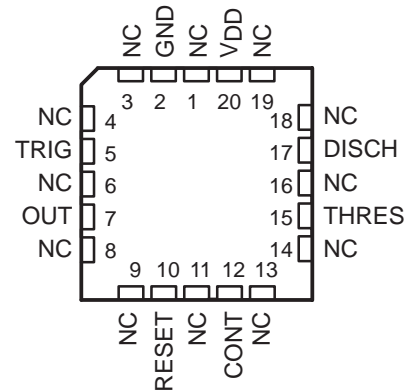
Like the NE555, the TLC555 has a trigger level equal to approximately one-third of the supply voltage and a threshold level equal to approximately two-thirds of the supply voltage. These levels can be altered by use of the control voltage terminal (CONT). When the trigger input (TRIG) falls below the trigger level, the flip-flop is set and the output goes high. If TRIG is above the trigger level and the threshold input (THRES) is above the threshold level, the flip-flop is reset and the output is low. The reset input (RESET) can override all other inputs and can be used to initiate a new timing cycle. If RESET is low, the flip-flop is reset and the output is low. Whenever the output is low, a low-impedance path is provided between the discharge terminal (DISCH) and GND. All unused inputs should be tied to an appropriate logic level to prevent false triggering.

While the CMOS output is capable of sinking over 100 mA and sourcing over 10 mA, the TLC555 exhibits greatly reduced supply-current spikes during output transitions. This minimizes the need for the large decoupling capacitors required by the NE555.

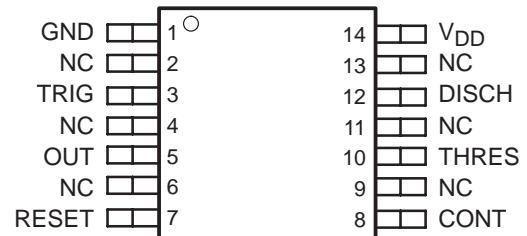
D, DB, JG, OR P PACKAGE
(TOP VIEW)



FK PACKAGE
(TOP VIEW)



PW PACKAGE
(TOP VIEW)



NC – No internal connection



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

LinCMOS is a trademark of Texas Instruments.

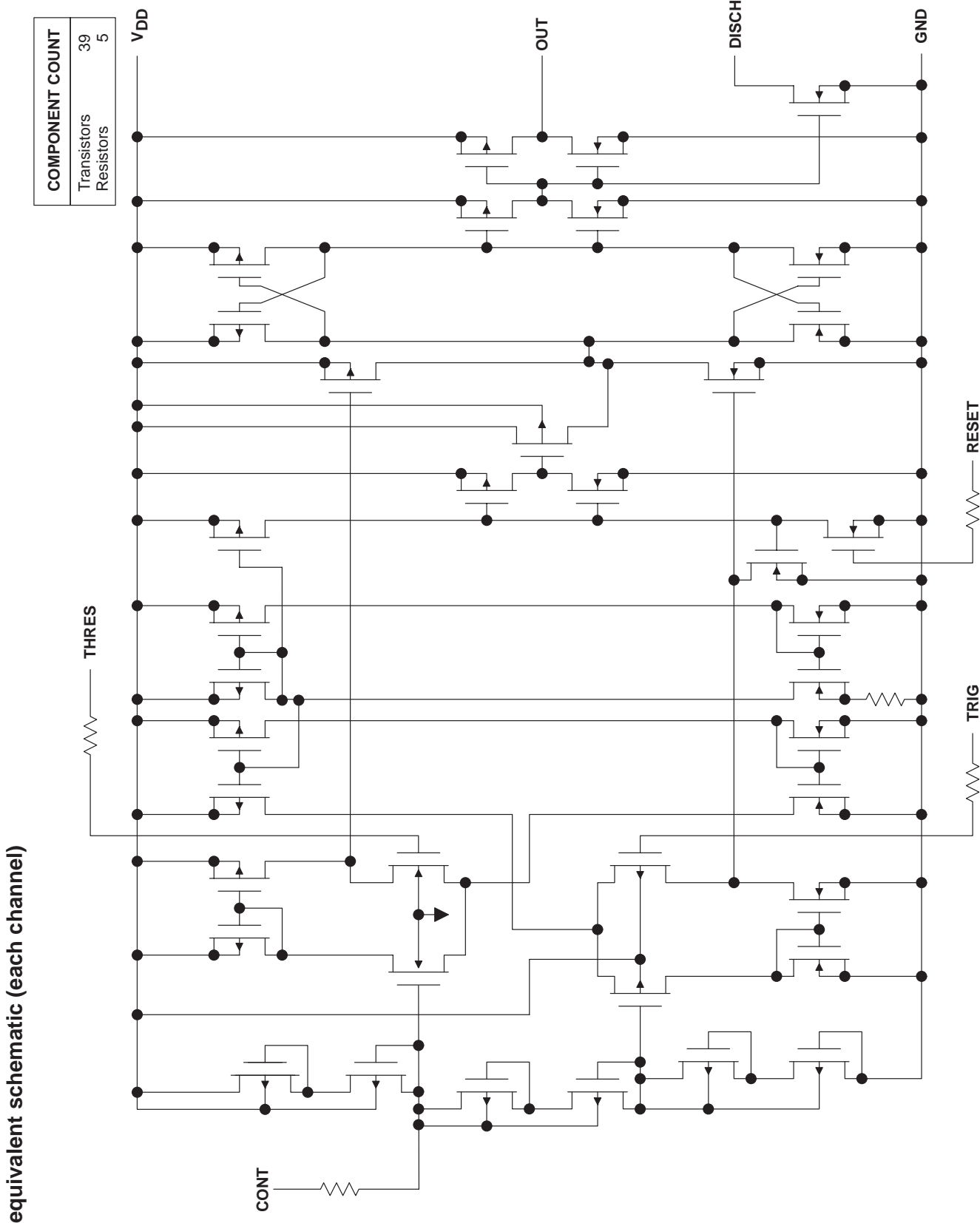
PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.



POST OFFICE BOX 655303 • DALLAS, TEXAS 75265

Copyright © 1983–2005, Texas Instruments Incorporated
On products compliant to MIL-PRF-38535, all parameters are tested unless otherwise noted. On all other products, production processing does not necessarily include testing of all parameters.

[查询"5962-89503012A"供应商](#)



electrical characteristics at specified free-air temperature, $V_{DD} = 2\text{ V}$ for TLC555C, $V_{DD} = 3\text{ V}$ for TLC555I

PARAMETER	TEST CONDITIONS	T_A^\dagger	TLC555C			TLC555I			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
V_{IT} Threshold voltage		25°C	0.95	1.33	1.65	1.6		2.4	V
		Full range	0.85		1.75	1.5		2.5	
I_{IT} Threshold current		25°C	10			10			pA
		MAX	75			150			
$V_{I(TRIG)}$ Trigger voltage		25°C	0.4	0.67	0.95	0.71	1	1.29	V
		Full range	0.3		1.05	0.61		1.39	
$I_{I(TRIG)}$ Trigger current		25°C	10			10			pA
		MAX	75			150			
$V_{I(RESET)}$ Reset voltage		25°C	0.4	1.1	1.5	0.4	1.1	1.5	V
		Full range	0.3		2	0.3		1.8	
$I_{I(RESET)}$ Reset current		25°C	10			10			pA
		MAX	75			150			
Control voltage (open circuit) as a percentage of supply voltage		MAX	66.7%			66.7%			
Discharge switch on-stage voltage	$I_{OL} = 1\text{ mA}$	25°C	0.03			0.03			V
		Full range	0.25			0.375			
Discharge switch off-stage current		25°C	0.1			0.1			nA
		MAX	0.5			120			
V_{OH} High-level output voltage	$I_{OH} = -300\text{ }\mu\text{A}$	25°C	1.5	1.9		2.5	2.85		V
		Full range	1.5			2.5			
V_{OL} Low-level output voltage	$I_{OL} = 1\text{ mA}$	25°C	0.07			0.07			V
		Full range	0.35			0.4			
I_{DD} Supply current	See Note 2	25°C	250			250			μA
		Full range	400			500			

† Full range is 0°C to 70°C for the TLC555C and -40°C to 85°C for the TLC555I. For conditions shown as MAX, use the appropriate value specified in the recommended operating conditions table.

NOTE 2: These values apply for the expected operating configurations in which THRES is connected directly to DISCH or to TRIG.

electrical characteristics at specified free-air temperature, $V_{DD} = 15\text{ V}$

PARAMETER	TEST CONDITIONS	T_A †	TLC555C			TLC555I			TLC555Q, TLC555M			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	
V_{IT} Threshold voltage		25°C	9.45	10	10.55	9.45	10	10.55	9.45	10	10.55	V
		Full range	9.35		10.65	9.35		10.65	9.35		10.65	
I_{IT} Threshold current		25°C		10			10			10		pA
		MAX		75			150			5000		
$V_{I(TRIG)}$ Trigger voltage		25°C	4.65	5	5.35	4.65	5	5.35	4.65	5	5.35	V
		Full range	4.55		5.45	4.55		5.45	4.55		5.45	
$I_{I(TRIG)}$ Trigger current		25°C		10			10			10		pA
		MAX		75			150			5000		
$V_{I(RESET)}$ Reset voltage		25°C	0.4	1.1	1.5	0.4	1.1	1.5	0.4	1.1	1.5	V
		Full range	0.3		1.8	0.3		1.8	0.3		1.8	
$I_{I(RESET)}$ Reset current		25°C		10			10			10		pA
		MAX		75			150			5000		
Control voltage (open circuit) as a percentage of supply voltage		MAX		66.7%			66.7%			66.7%		
Discharge switch on-state voltage	$I_{OL} = 100\text{ mA}$	25°C		0.77	1.7		0.77	1.7		0.77	1.7	V
		Full range			1.8			1.8			1.8	
Discharge switch off-state current		25°C		0.1			0.1			0.1		nA
		MAX		0.5			120			120		
V_{OH} High-level output voltage	$I_{OH} = -10\text{ mA}$	25°C	12.5	14.2		12.5	14.2		12.5	14.2		V
		Full range	12.5			12.5			12.5			
	$I_{OH} = -5\text{ mA}$	25°C	13.5	14.6		13.5	14.6		13.5	14.6		
		Full range	13.5			13.5			13.5			
	$I_{OH} = -1\text{ mA}$	25°C	14.2	14.9		14.2	14.9		14.2	14.9		
		Full range	14.2			14.2			14.2			
V_{OL} Low-level output voltage	$I_{OL} = 100\text{ mA}$	25°C		1.28	3.2		1.28	3.2		1.28	3.2	V
		Full range			3.6			3.7			3.8	
	$I_{OL} = 50\text{ mA}$	25°C		0.63	1		0.63	1		0.63	1	
		Full range			1.3			1.4			1.5	
	$I_{OL} = 10\text{ mA}$	25°C		0.12	0.3		0.12	0.3		0.12	0.3	
		Full range			0.4			0.4			0.45	
I_{DD} Supply current	See Note 2	25°C		360	600		360	600		360	600	μA
		Full range			800			900			1000	

† Full range is 0°C to 70°C for TLC555C, -40°C to 85°C for TLC555I, -40°C to 125°C for the TLC555Q, and -55°C to 125°C for TLC555M. For conditions shown as MAX, use the appropriate value specified in the recommended operating conditions table.

NOTE 2: These values apply for the expected operating configurations in which THRES is connected directly to DISCH or TRIG.

TLC555 LinCMOS™ TIMER

SLF555 (Rev. 1998) REF ID: A5550312A 12/98 FEBRUARY 2005

查看"5962-095031-12A"供应商

operating characteristics, $V_{DD} = 5\text{ V}$, $T_A = 25^\circ\text{C}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Initial error of timing interval‡	$V_{DD} = 5\text{ V to }15\text{ V}$, $R_A = R_B = 1\text{ k}\Omega\text{ to }100\text{ k}\Omega$, $C_T = 0.1\text{ }\mu\text{F}$, See Note 3		1%	3%	
Supply voltage sensitivity of timing interval			0.1	0.5	%/V
t_r Output pulse rise time	$R_L = 10\text{ M}\Omega$, $C_L = 10\text{ pF}$		20	75	ns
t_f Output pulse fall time			15	60	
f_{max} Maximum frequency in astable mode	$R_A = 470\text{ }\Omega$, $C_T = 200\text{ pF}$, $R_B = 200\text{ }\Omega$, See Note 3	1.2	2.1		MHz

‡ Timing interval error is defined as the difference between the measured value and the average value of a random sample from each process run.

NOTE 3: R_A , R_B , and C_T are as defined in Figure 1.

electrical characteristics at $V_{DD} = 5\text{ V}$, $T_A = 25^\circ\text{C}$

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
V_{IT} Threshold voltage		2.8	3.3	3.8	V
I_{IT} Threshold current			10		pA
$V_{I(TRIG)}$ Trigger voltage		1.36	1.66	1.96	V
$I_{I(TRIG)}$ Trigger current			10		pA
$V_{I(RESET)}$ Reset voltage		0.4	1.1	1.5	V
$I_{I(RESET)}$ Reset current			10		pA
Control voltage (open circuit) as a percentage of supply voltage			66.7%		
Discharge switch on-state voltage	$I_{OL} = 10\text{ mA}$		0.14	0.5	V
Discharge switch off-state current			0.1		nA
V_{OH} High-level output voltage	$I_{OH} = -1\text{ mA}$	4.1	4.8		V
V_{OL} Low-level output voltage	$I_{OL} = 8\text{ mA}$		0.21	0.4	V
	$I_{OL} = 5\text{ mA}$		0.13	0.3	
	$I_{OL} = 3.2\text{ mA}$		0.08	0.3	
I_{DD} Supply current	See Note 2		170	350	μA

NOTE 2: These values apply for the expected operating configurations in which THRES is connected directly to DISCH or TRIG.

TYPICAL CHARACTERISTICS

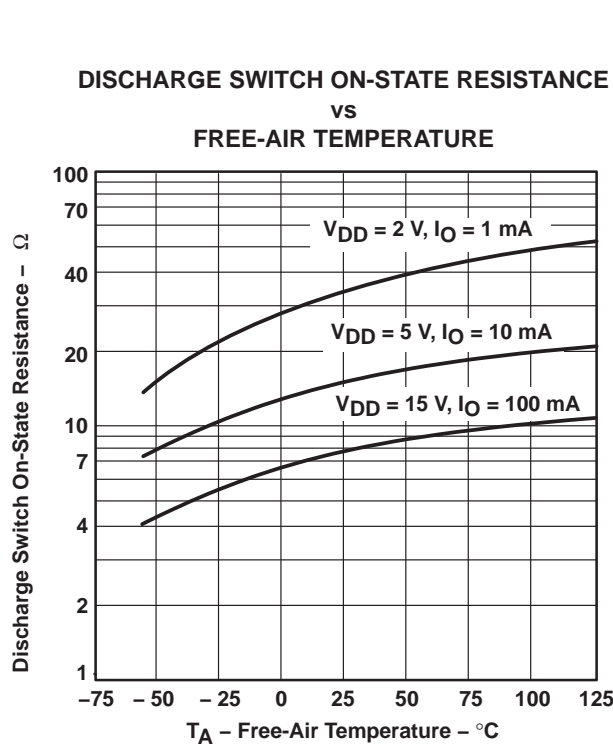
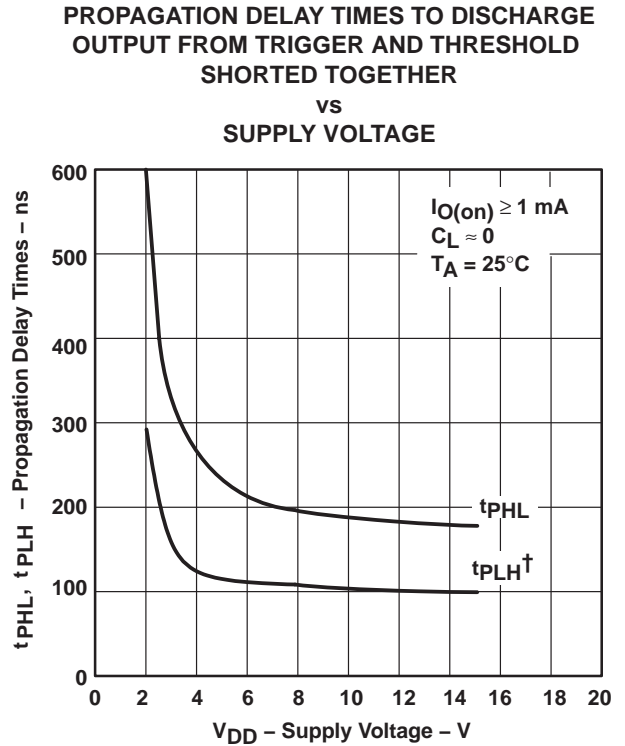


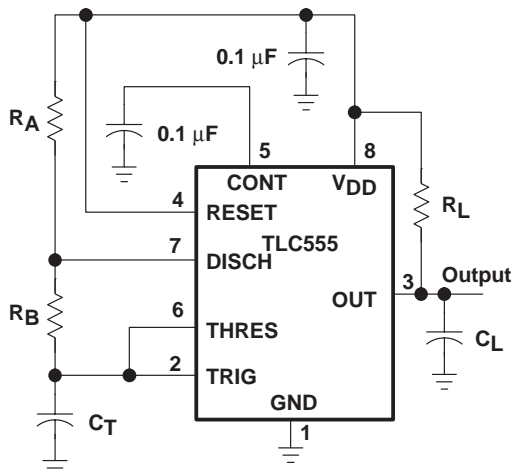
Figure 1



† The effects of the load resistance on these values must be taken into account separately.

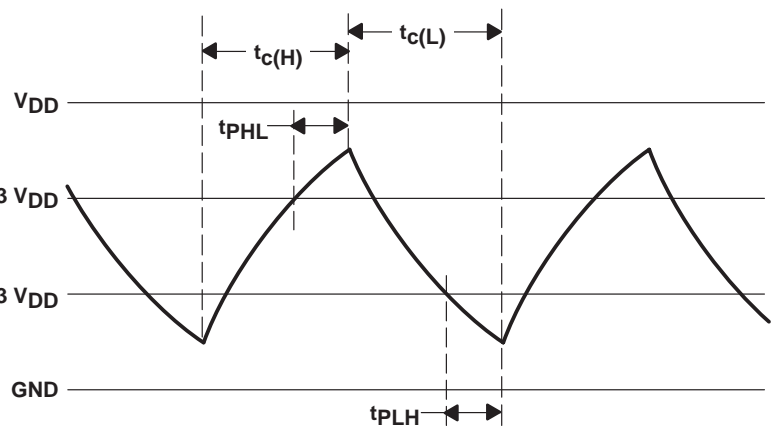
Figure 2

APPLICATION INFORMATION



Pin numbers shown are for all packages except the FK package.

CIRCUIT



TRIGGER AND THRESHOLD VOLTAGE WAVEFORM

Figure 3. Astable Operation

APPLICATION INFORMATION

Connecting TRIG to THRES, as shown in Figure 3, causes the timer to run as a multivibrator. The capacitor C_T charges through R_A and R_B to the threshold voltage level (approximately $0.67 V_{DD}$) and then discharges through R_B only to the value of the trigger voltage level (approximately $0.33 V_{DD}$). The output is high during the charging cycle ($t_{c(H)}$) and low during the discharge cycle ($t_{c(L)}$). The duty cycle is controlled by the values of R_A , R_B , and C_T as shown in the equations below.

$$t_{c(H)} \approx C_T (R_A + R_B) \ln 2 \quad (\ln 2 = 0.693)$$

$$t_{c(L)} \approx C_T R_B \ln 2$$

$$\text{Period} = t_{c(H)} + t_{c(L)} \approx C_T (R_A + 2R_B) \ln 2$$

$$\text{Output driver duty cycle} = \frac{t_{c(L)}}{t_{c(H)} + t_{c(L)}} \approx 1 - \frac{R_B}{R_A + 2R_B}$$

$$\text{Output waveform duty cycle} = \frac{t_{c(H)}}{t_{c(H)} + t_{c(L)}} \approx \frac{R_B}{R_A + 2R_B}$$

The 0.1- μF capacitor at CONT in Figure 3 decreases the period by about 10%.

The formulas shown above do not allow for any propagation delay times from the TRIG and THRES inputs to DISCH. These delay times add directly to the period and create differences between calculated and actual values that increase with frequency. In addition, the internal on-state resistance r_{on} during discharge adds to R_B to provide another source of timing error in the calculation when R_B is very low or r_{on} is very high.

The equations below provide better agreement with measured values.

$$t_{c(H)} = C_T (R_A + R_B) \ln \left[3 - \exp \left(\frac{-t_{PLH}}{C_T (R_B + r_{on})} \right) \right] + t_{PLH}$$

$$t_{c(L)} = C_T (R_B + r_{on}) \ln \left[3 - \exp \left(\frac{-t_{PHL}}{C_T (R_A + R_B)} \right) \right] + t_{PHL}$$

These equations and those given earlier are similar in that a time constant is multiplied by the logarithm of a number or function. The limit values of the logarithmic terms must be between $\ln 2$ at low frequencies and $\ln 3$ at extremely high frequencies. For a duty cycle close to 50%, an appropriate constant for the logarithmic terms can be substituted

with good results. Duty cycles less than 50% $\frac{t_{c(H)}}{t_{c(H)} + t_{c(L)}}$ require that $\frac{t_{c(H)}}{t_{c(L)}} < 1$ and possibly $R_A \leq r_{on}$. These

conditions can be difficult to obtain.

In monostable applications, the trip point on TRIG can be set by a voltage applied to CONT. An input voltage between 10% and 80% of the supply voltage from a resistor divider with at least 500- μA bias provides good results.

PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
5962-89503012A	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	Level-NC-NC-NC
5962-8950301PA	ACTIVE	CDIP	JG	8	1	TBD	A42 SNPB	Level-NC-NC-NC
TLC555CD	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLC555CDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLC555CDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLC555CDRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLC555CP	ACTIVE	PDIP	P	8	50	Pb-Free (RoHS)	CU NIPDAU	Level-NC-NC-NC
TLC555CPE4	ACTIVE	PDIP	P	8	50	Pb-Free (RoHS)	CU NIPDAU	Level-NC-NC-NC
TLC555CPSR	ACTIVE	SO	PS	8	2000	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1YEAR/ Level-1-220C-UNLIM
TLC555CPW	ACTIVE	TSSOP	PW	14	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLC555CPWG4	ACTIVE	TSSOP	PW	14	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLC555CPWR	ACTIVE	TSSOP	PW	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLC555CPWRG4	ACTIVE	TSSOP	PW	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLC555ID	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLC555IDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLC555IDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLC555IDRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLC555IP	ACTIVE	PDIP	P	8	50	Pb-Free (RoHS)	CU NIPDAU	Level-NC-NC-NC
TLC555IPE4	ACTIVE	PDIP	P	8	50	Pb-Free (RoHS)	CU NIPDAU	Level-NC-NC-NC
TLC555MFKB	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	Level-NC-NC-NC
TLC555MJG	ACTIVE	CDIP	JG	8	1	TBD	A42 SNPB	Level-NC-NC-NC
TLC555MJGB	ACTIVE	CDIP	JG	8	1	TBD	A42 SNPB	Level-NC-NC-NC
TLC555MP	OBSOLETE	PDIP	P	8		TBD	Call TI	Call TI
TLC555QDR	ACTIVE	SOIC	D	8	2500	TBD	CU NIPDAU	Level-1-220C-UNLIM

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS) or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

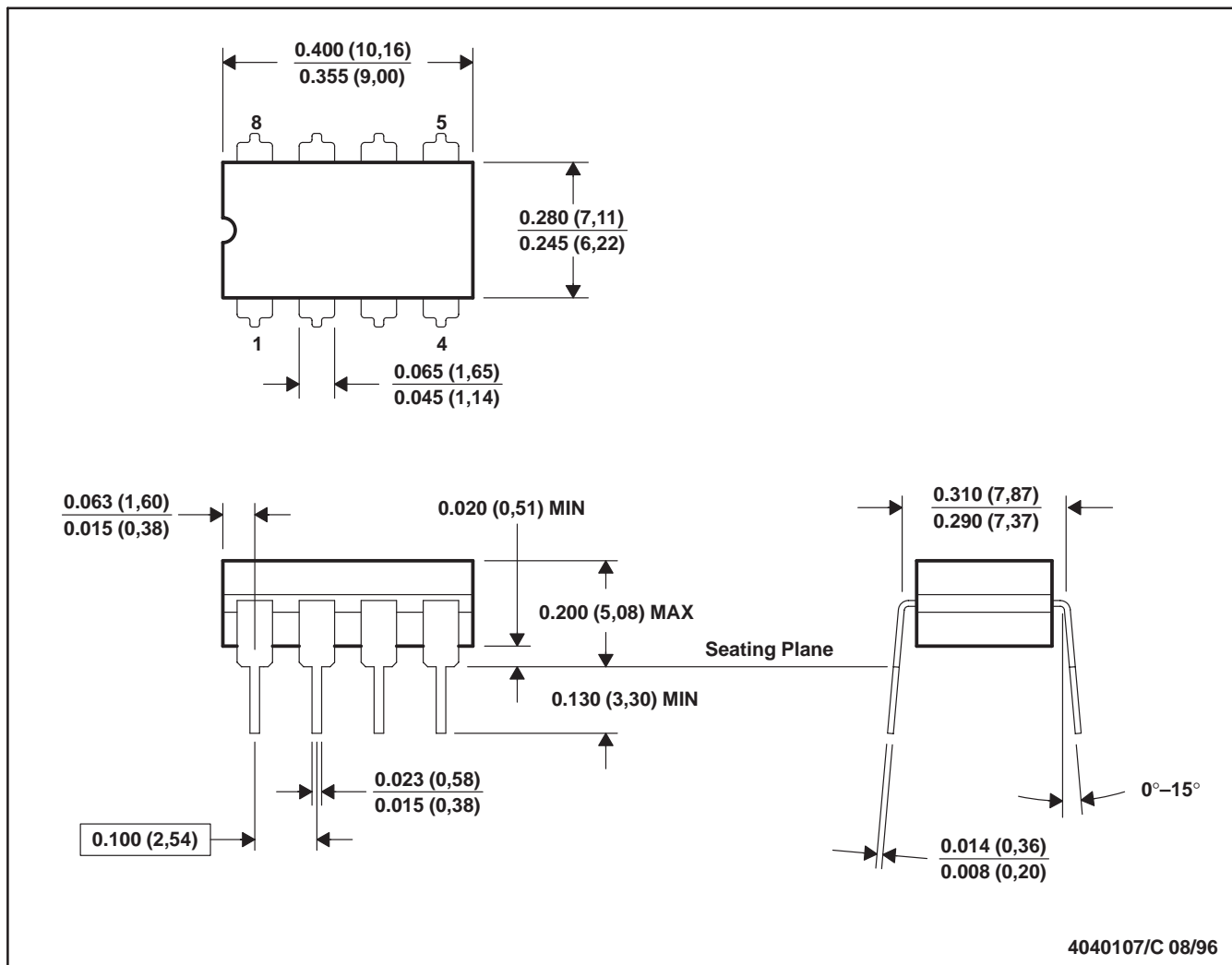
(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

Important Information and Disclaimer:The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

JG (R-GDIP-T8)

CERAMIC DUAL-IN-LINE

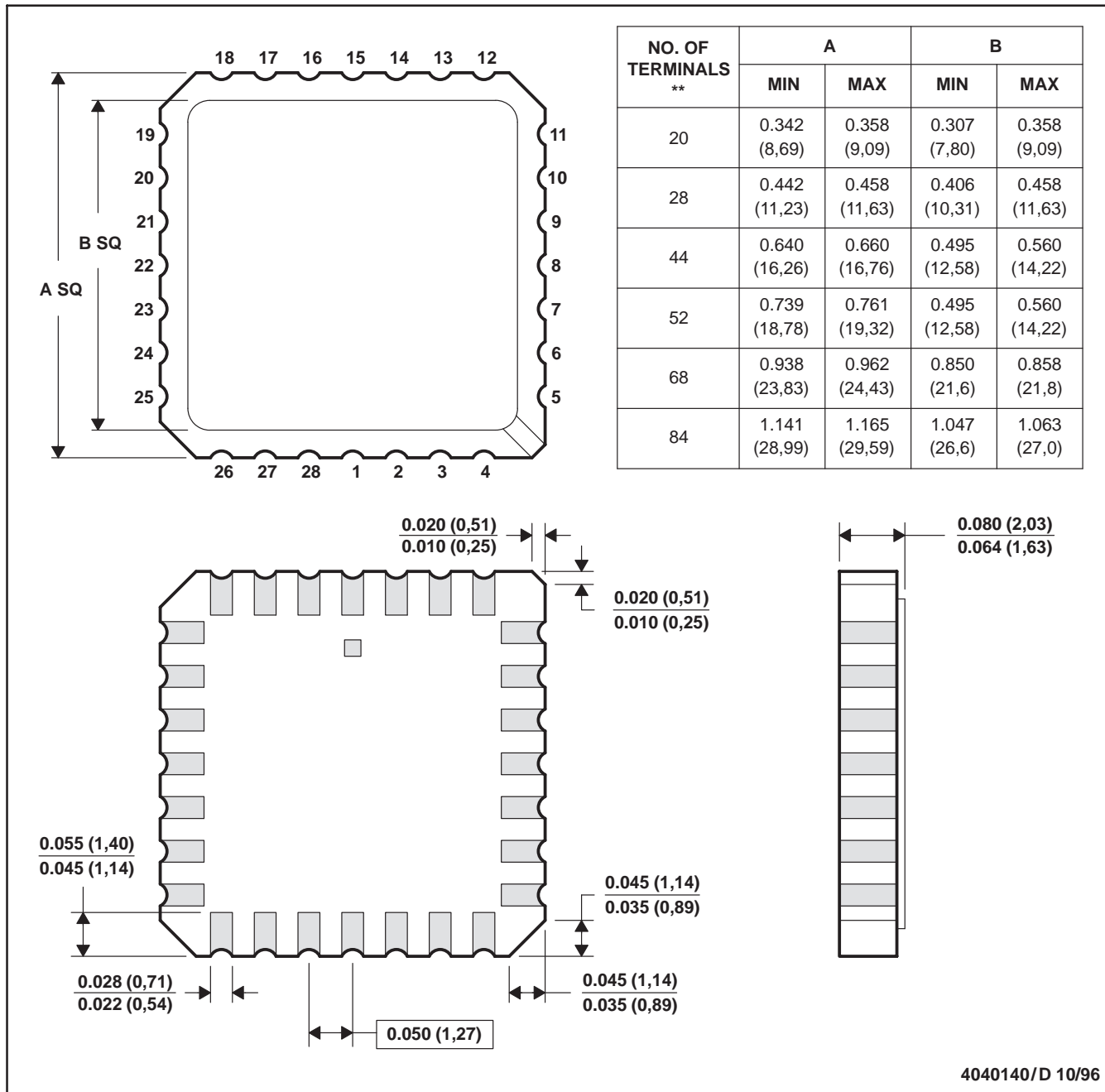


- NOTES: A. All linear dimensions are in inches (millimeters).
 B. This drawing is subject to change without notice.
 C. This package can be hermetically sealed with a ceramic lid using glass frit.
 D. Index point is provided on cap for terminal identification.
 E. Falls within MIL STD 1835 GDIP1-T8

FK (S-CQCC-N**)

LEADLESS CERAMIC CHIP CARRIER

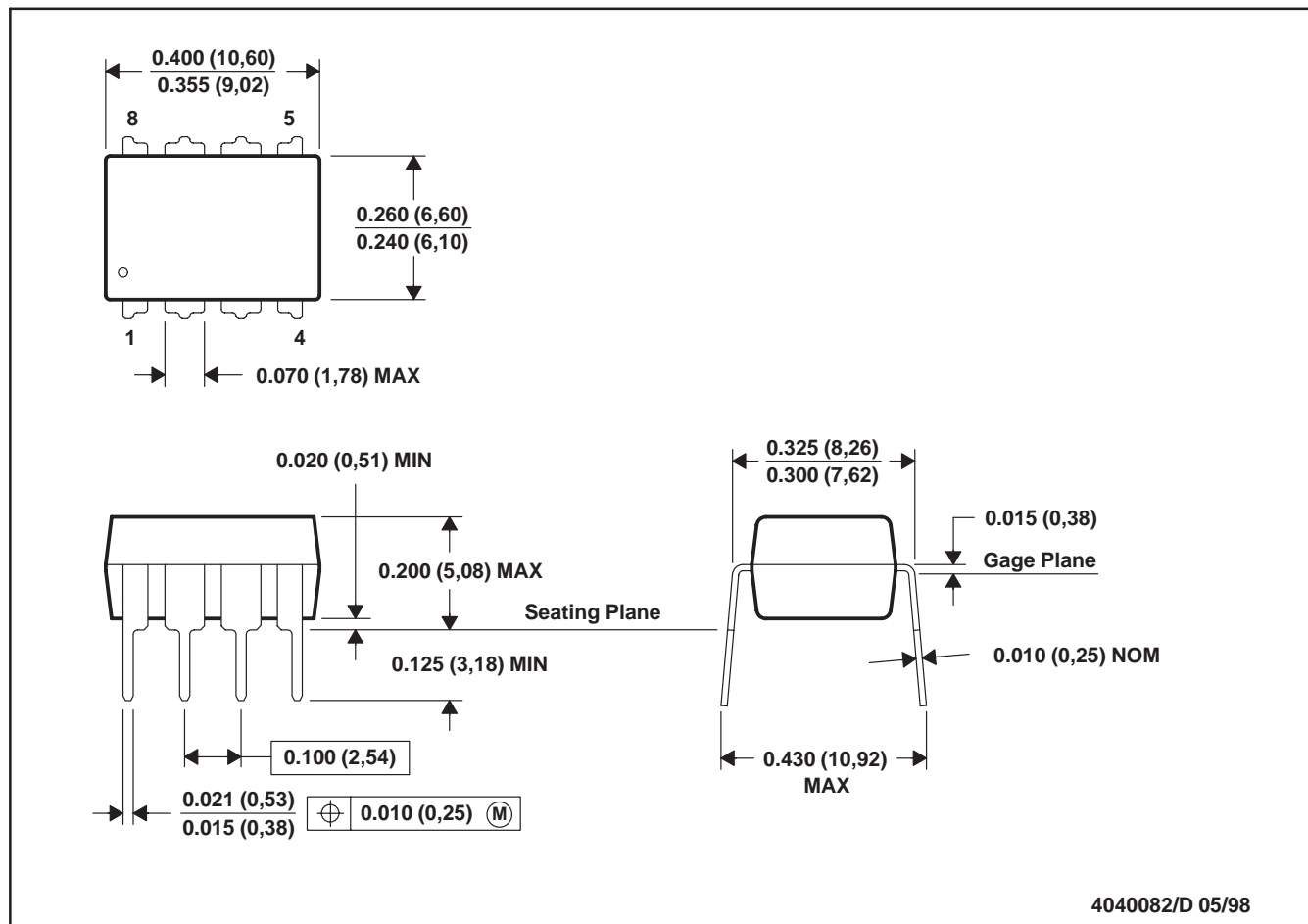
28 TERMINAL SHOWN



- NOTES:
- A. All linear dimensions are in inches (millimeters).
 - B. This drawing is subject to change without notice.
 - C. This package can be hermetically sealed with a metal lid.
 - D. The terminals are gold plated.
 - E. Falls within JEDEC MS-004

P (R-PDIP-T8)

PLASTIC DUAL-IN-LINE



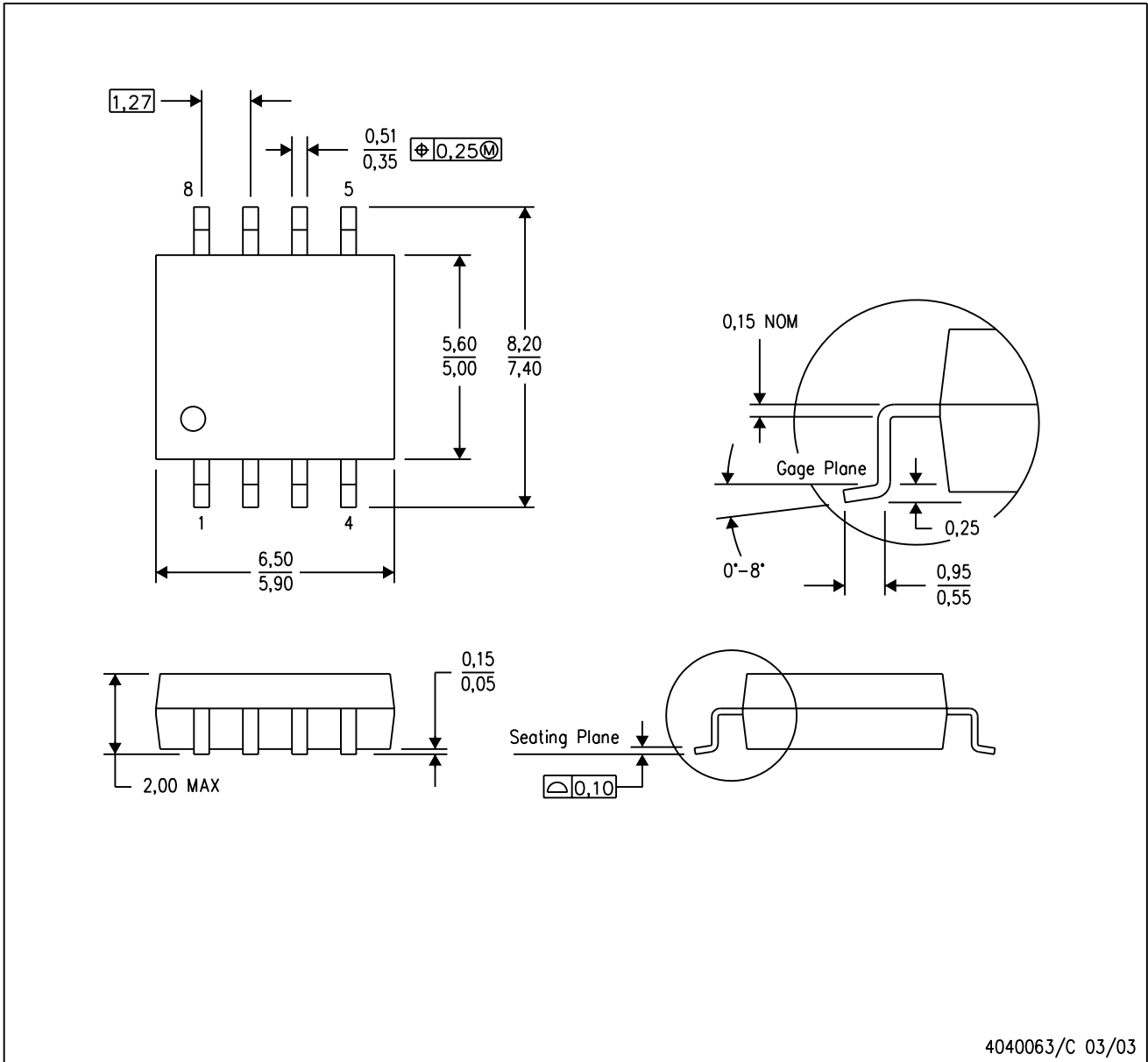
- NOTES: A. All linear dimensions are in inches (millimeters).
 B. This drawing is subject to change without notice.
 C. Falls within JEDEC MS-001

For the latest package information, go to http://www.ti.com/sc/docs/package/pkg_info.htm

MECHANICAL DATA

PS (R-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE

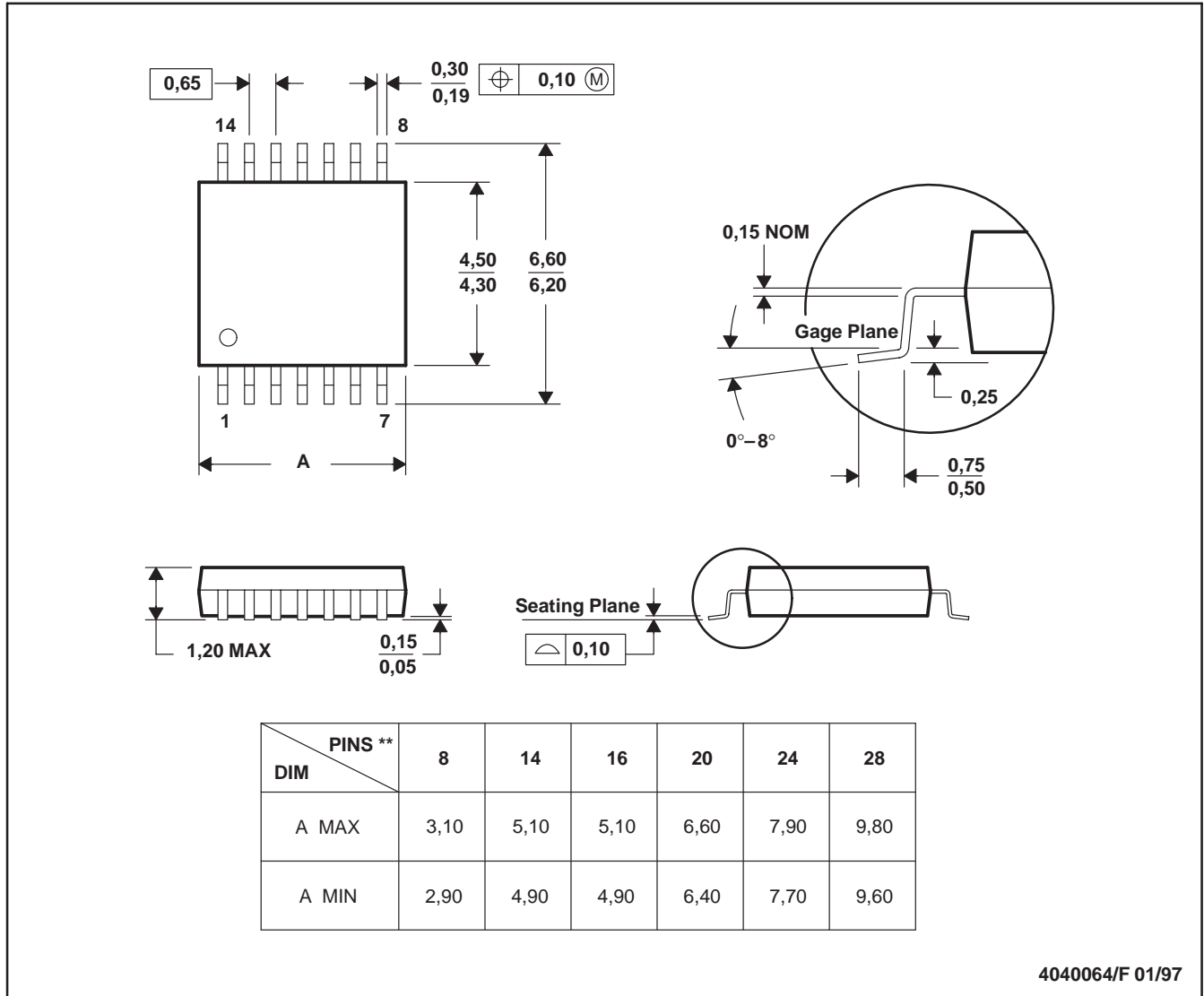


- NOTES:
- A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.

PW (R-PDSO-G**)

PLASTIC SMALL-OUTLINE PACKAGE

14 PINS SHOWN



- NOTES: A. All linear dimensions are in millimeters.
 B. This drawing is subject to change without notice.
 C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.
 D. Falls within JEDEC MO-153

IMPORTANT NOTICE

Texas Instruments Incorporated and its subsidiaries (TI) reserve the right to make corrections, modifications, enhancements, improvements, and other changes to its products and services at any time and to discontinue any product or service without notice. Customers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All products are sold subject to TI's terms and conditions of sale supplied at the time of order acknowledgment.

TI warrants performance of its hardware products to the specifications applicable at the time of sale in accordance with TI's standard warranty. Testing and other quality control techniques are used to the extent TI deems necessary to support this warranty. Except where mandated by government requirements, testing of all parameters of each product is not necessarily performed.

TI assumes no liability for applications assistance or customer product design. Customers are responsible for their products and applications using TI components. To minimize the risks associated with customer products and applications, customers should provide adequate design and operating safeguards.

TI does not warrant or represent that any license, either express or implied, is granted under any TI patent right, copyright, mask work right, or other TI intellectual property right relating to any combination, machine, or process in which TI products or services are used. Information published by TI regarding third-party products or services does not constitute a license from TI to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

Reproduction of information in TI data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. Reproduction of this information with alteration is an unfair and deceptive business practice. TI is not responsible or liable for such altered documentation.

Resale of TI products or services with statements different from or beyond the parameters stated by TI for that product or service voids all express and any implied warranties for the associated TI product or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

Following are URLs where you can obtain information on other Texas Instruments products and application solutions:

Products		Applications	
Amplifiers	amplifier.ti.com	Audio	www.ti.com/audio
Data Converters	dataconverter.ti.com	Automotive	www.ti.com/automotive
DSP	dsp.ti.com	Broadband	www.ti.com/broadband
Interface	interface.ti.com	Digital Control	www.ti.com/digitalcontrol
Logic	logic.ti.com	Military	www.ti.com/military
Power Mgmt	power.ti.com	Optical Networking	www.ti.com/opticalnetwork
Microcontrollers	microcontroller.ti.com	Security	www.ti.com/security
		Telephony	www.ti.com/telephony
		Video & Imaging	www.ti.com/video
		Wireless	www.ti.com/wireless

Mailing Address: Texas Instruments
Post Office Box 655303 Dallas, Texas 75265